

Introduction to Electronics

Part 4: Non-Linear Element

L19: Non-Linear Analysis



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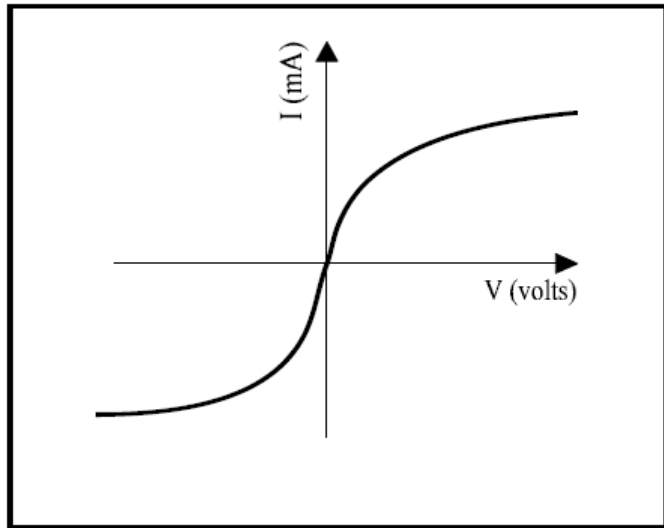
References

- To prepare these slides, materials from following books have been used.
 - Foundations of Analog and Digital Electronic Circuits by A. Agarwal and J. H. Lang, Elsevier

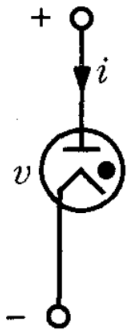
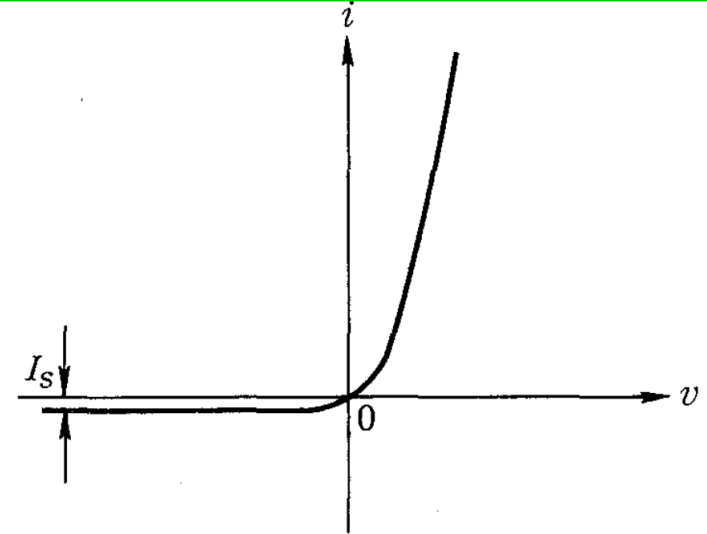
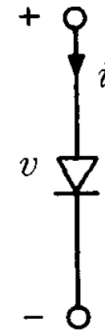
Generalized Time-Invariant Resistor



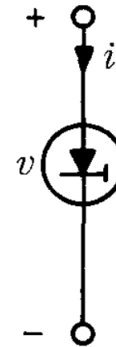
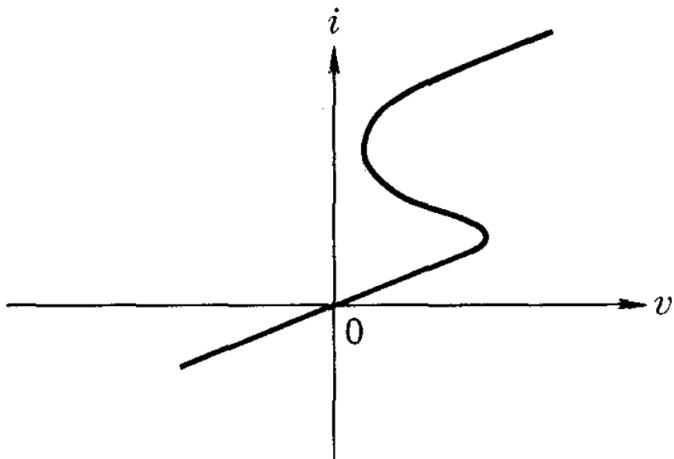
Bulb



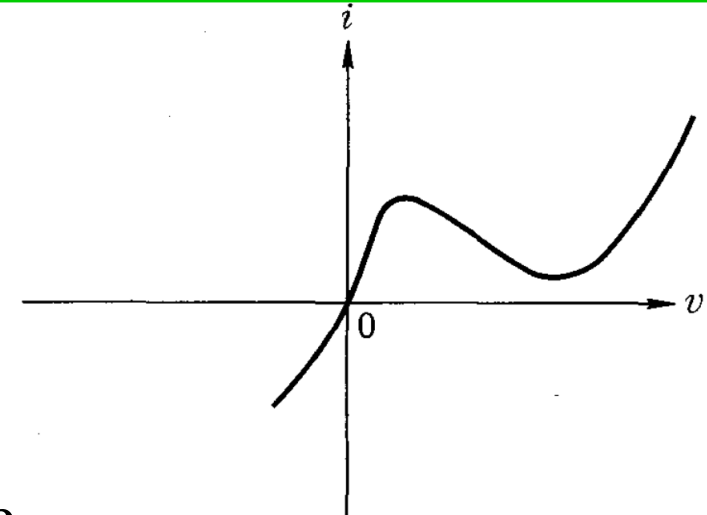
PN Diode



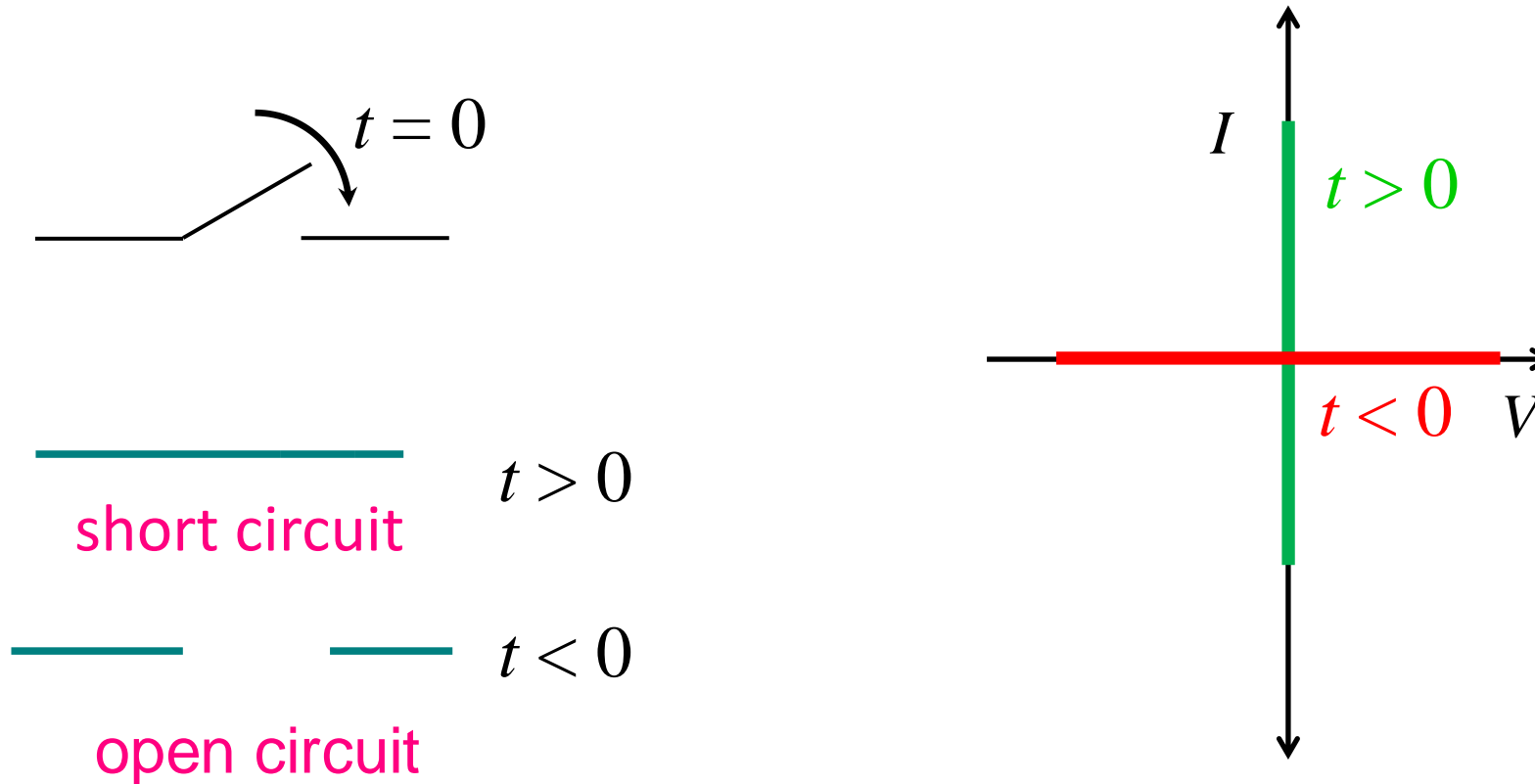
Gas Diode



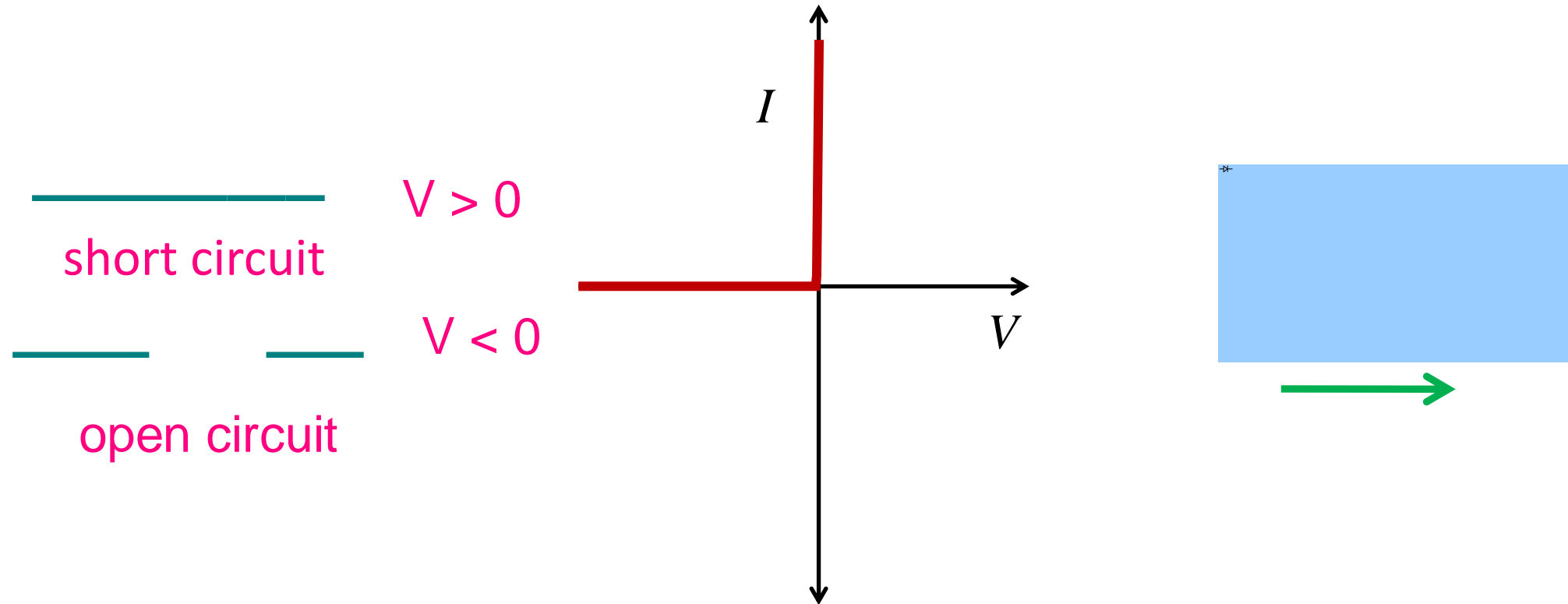
Tunnel Diode



Switch: Linear Time-Varying Resistor



Unidirectional Device: Non-linear Time-invariant Resistor



I-V Characteristics: Non-linear Behavior

Applied voltage = v_D

Diode current:

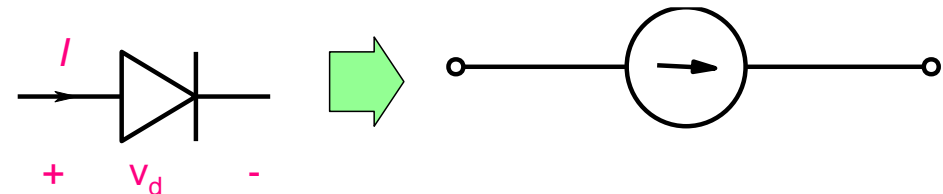
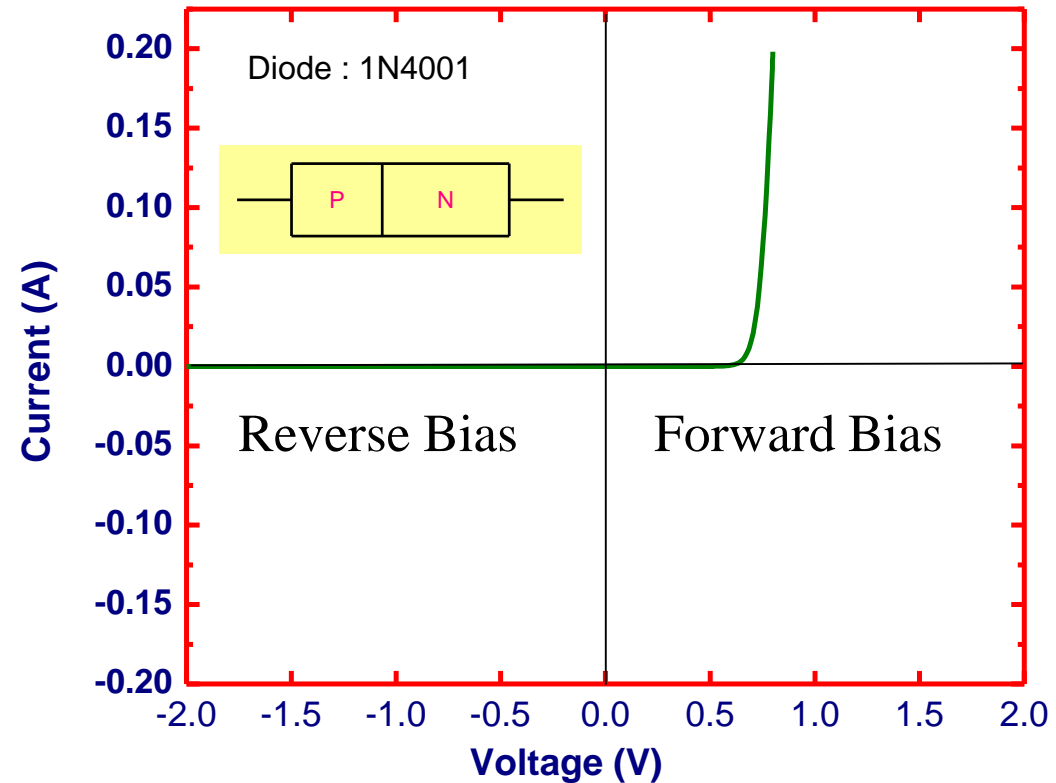
$$i_D = I_S \left(\exp \left(\frac{v_D}{nV_T} \right) - 1 \right)$$

I_S : Reverse saturation current

n : ideality factor (= 1 for ideal diodes)

$$V_T = \frac{kT}{q} \approx 26\text{mV at } T = 300\text{K}$$

□ How to analyze circuits containing diodes?



Forward and Reverse Bias

$$I_D = I_S \left(\exp \left(\frac{v_D}{V_T} \right) - 1 \right)$$

□ Forward Bias:

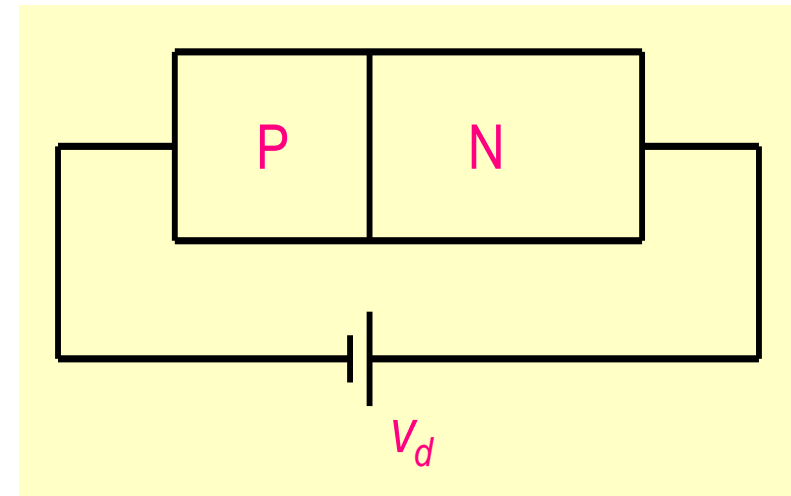
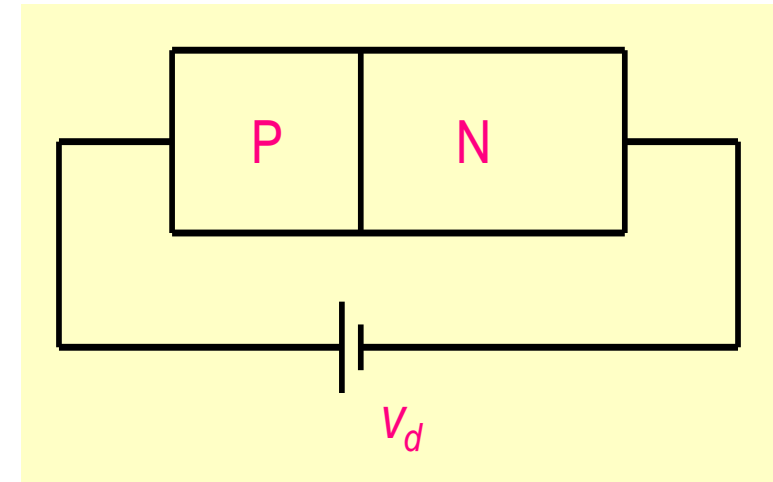
$$v_d \gg V_T = 26mV$$

$$i_D \approx I_S \times \exp \left(\frac{v_d}{V_T} \right)$$

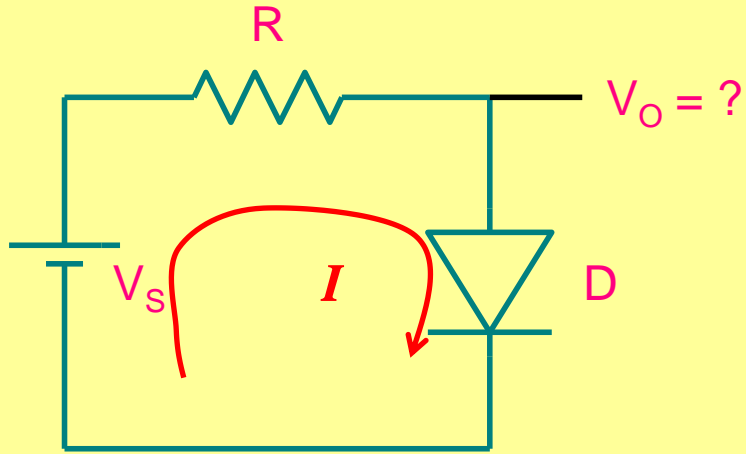
□ Reverse Bias:

$$v_d = -v_R \quad |v_R| \gg V_T$$

$$i_D = I_S \left(\exp \left(-\frac{v_R}{V_T} \right) - 1 \right) \approx -I_S$$



Method of Approximation

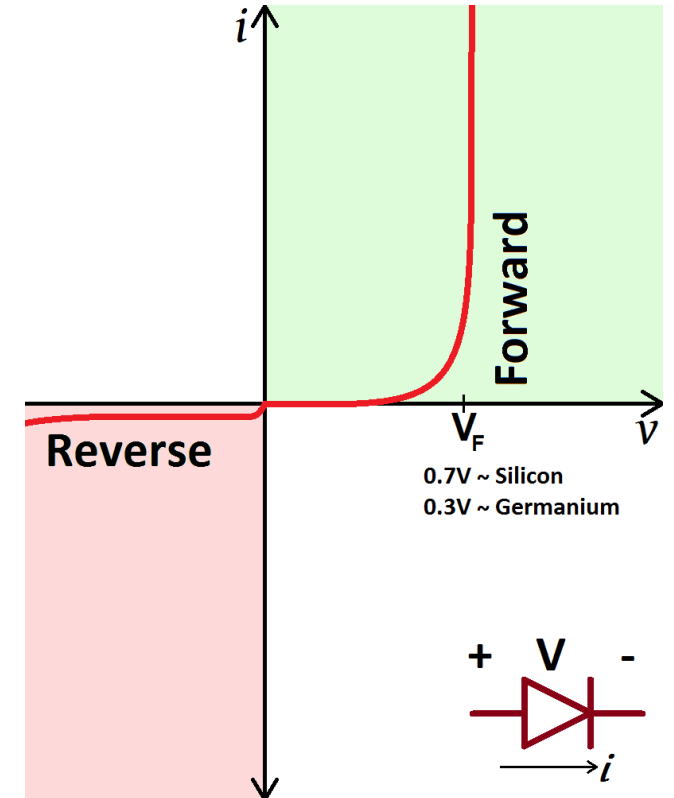


$$V_S = R I + V_D \quad I = I_S \left(e^{\frac{V_D}{V_T}} - 1 \right)$$

2 equations, 2 variables

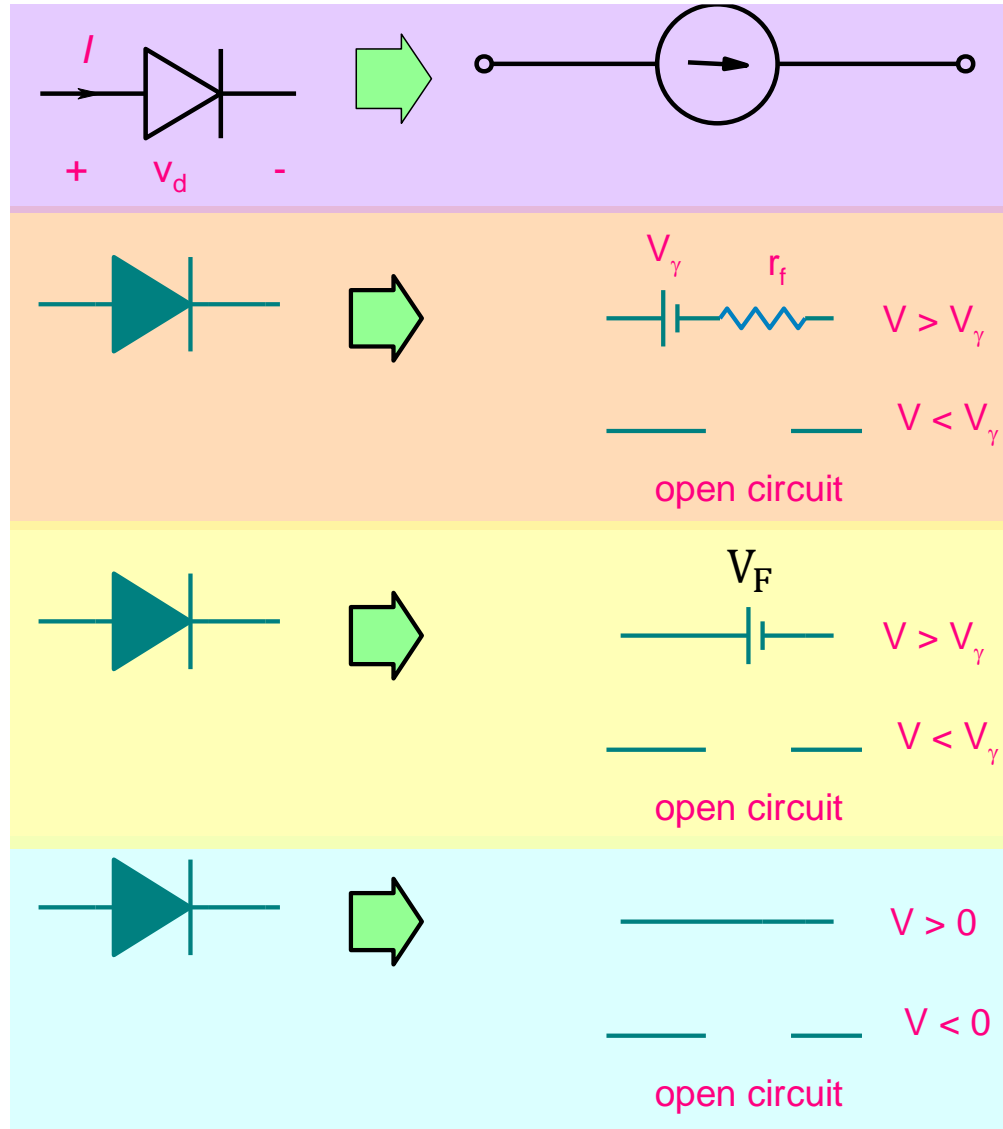
$$V_S = R I_S \left(e^{\frac{V_D}{V_T}} - 1 \right) + V_D$$

- Non-linear equation: How to solve?
 - Numerical methods, graphical method, analytical method, etc.
- We can however approximate its behavior with piecewise linear one
 - I-V graph is approximated by joining two or more straight lines

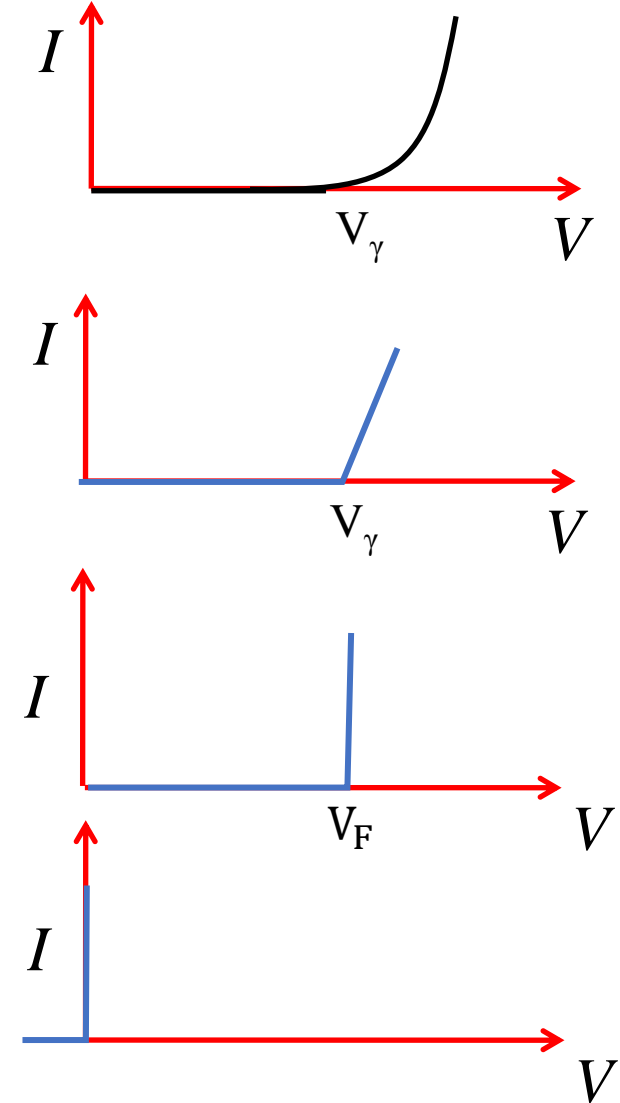


Diode: Approximate I-V Models

Simplicity



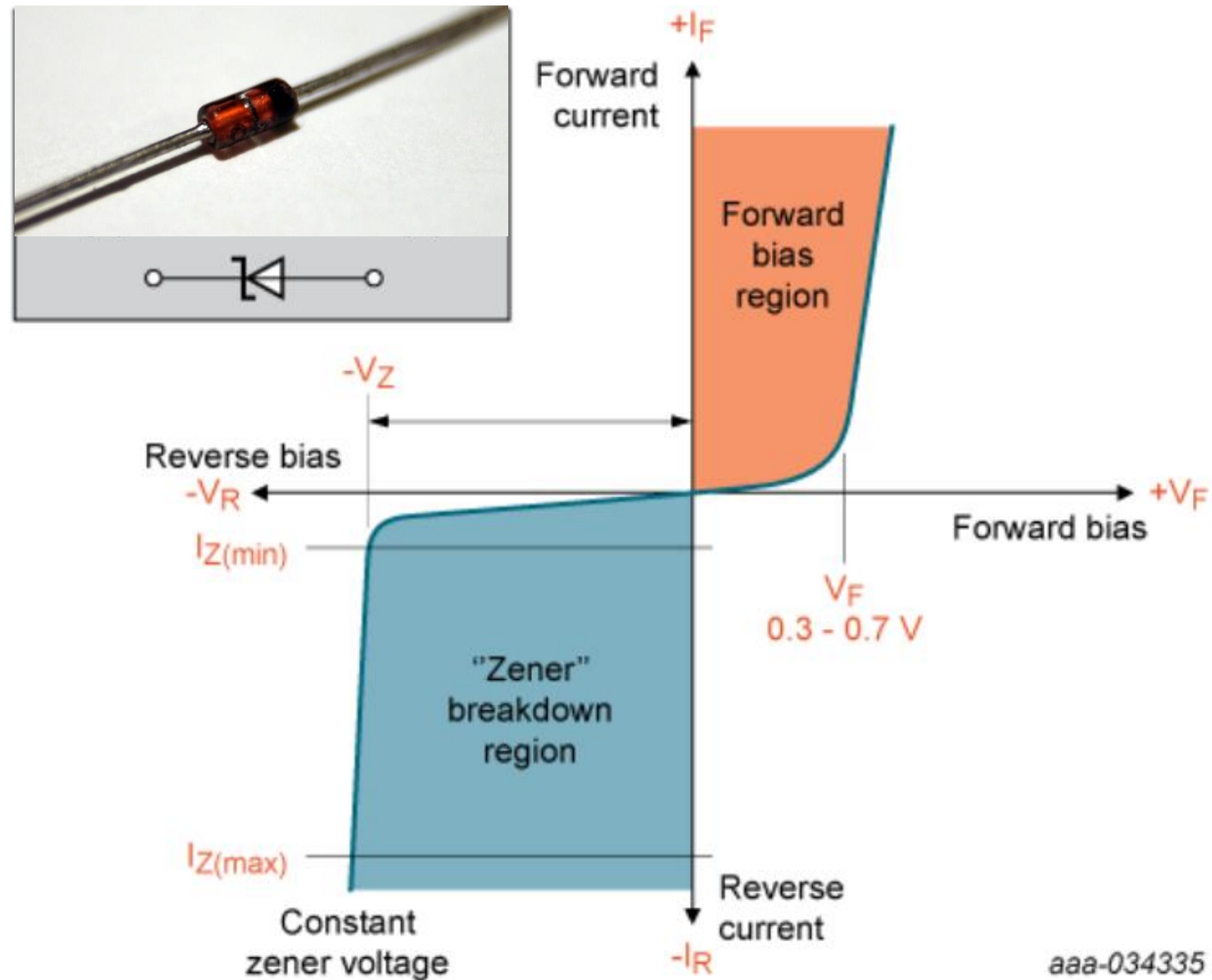
Accuracy



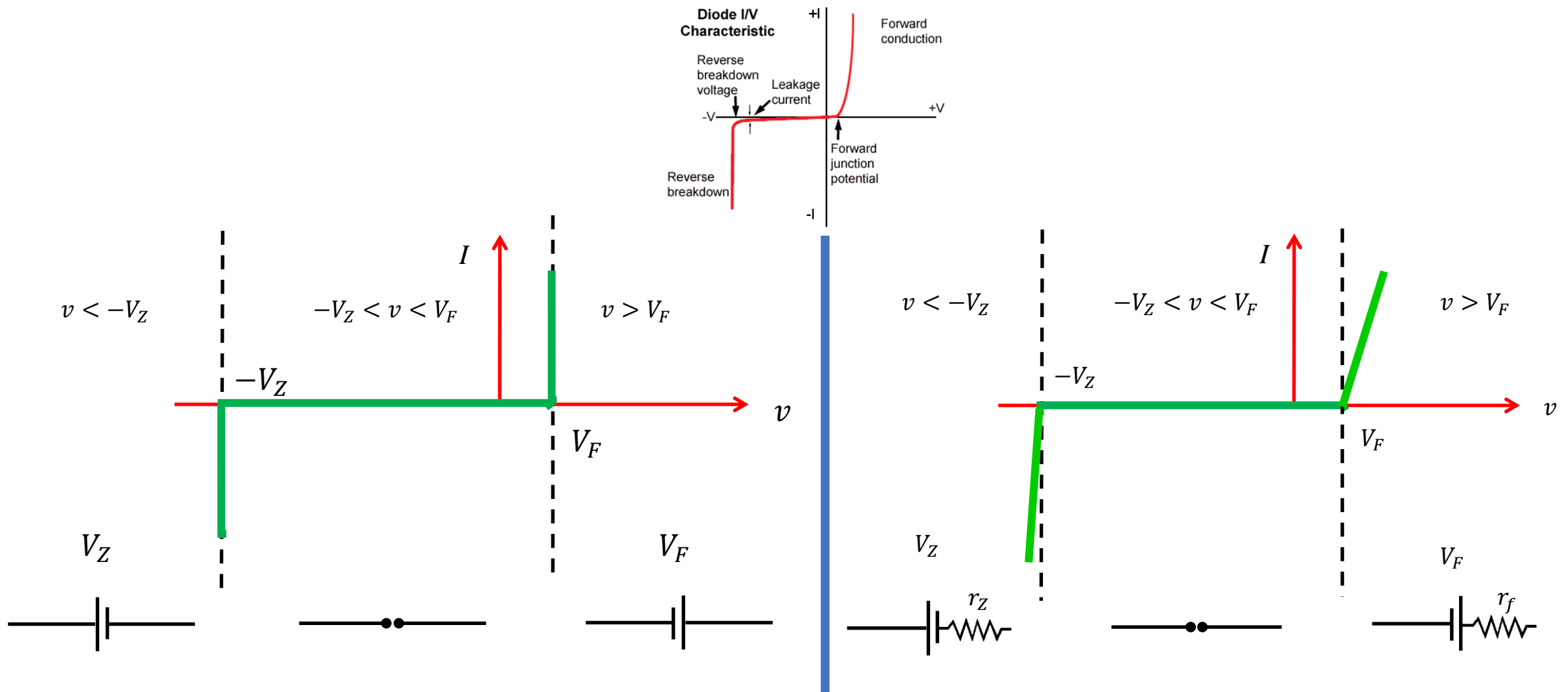
Self-Consistent Analysis

- How to know in which state diode is?
 - Easier if the voltage is known.
 - Otherwise
 - Analyze circuit assuming diode is forward biased
 - Check assumption ($I > 0$?)
 - Analyze circuit assuming diode is reverse biased
 - Check assumption ($V < 0$?)
 - Select the consistent one.
- What if 2 diodes: 4 possible circuits, only 1 will be valid
- N diodes $\Rightarrow 2^N$ circuits, only one will be valid

Breakdown and Zener Diode

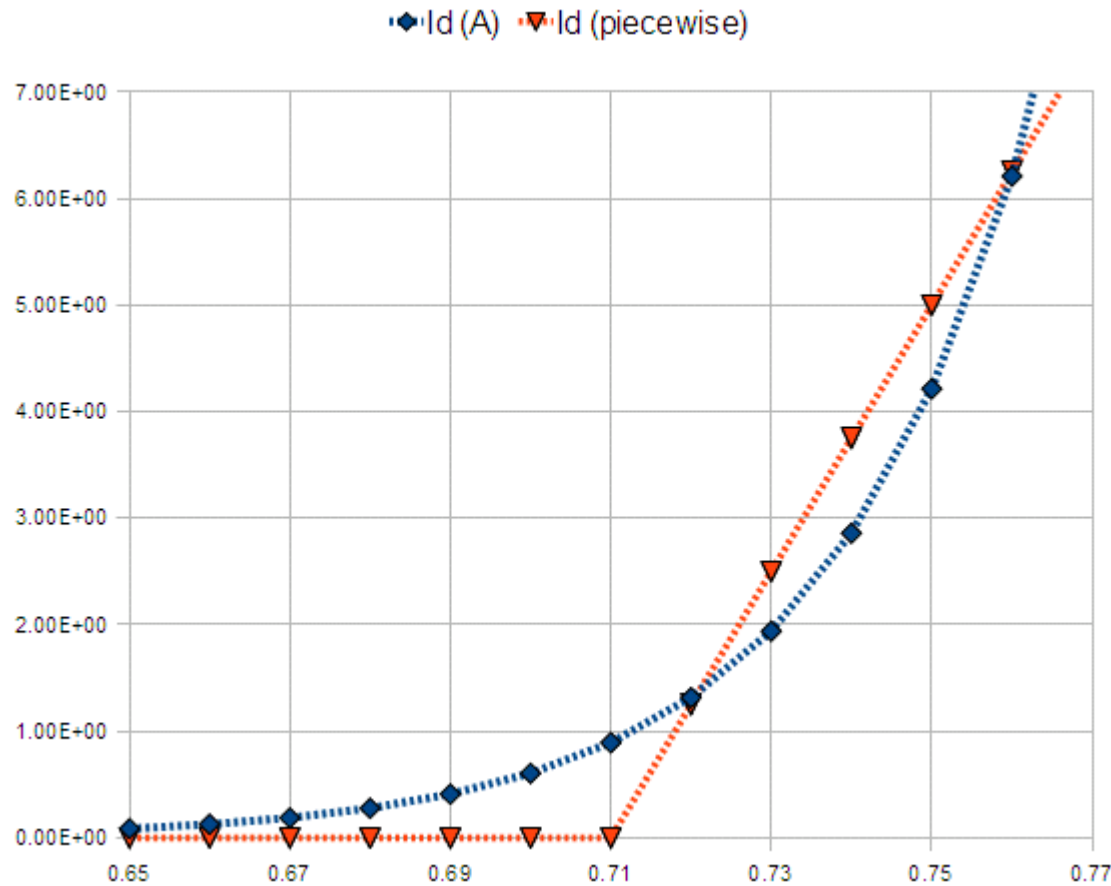


Zener Diode: Approximation I-V Model

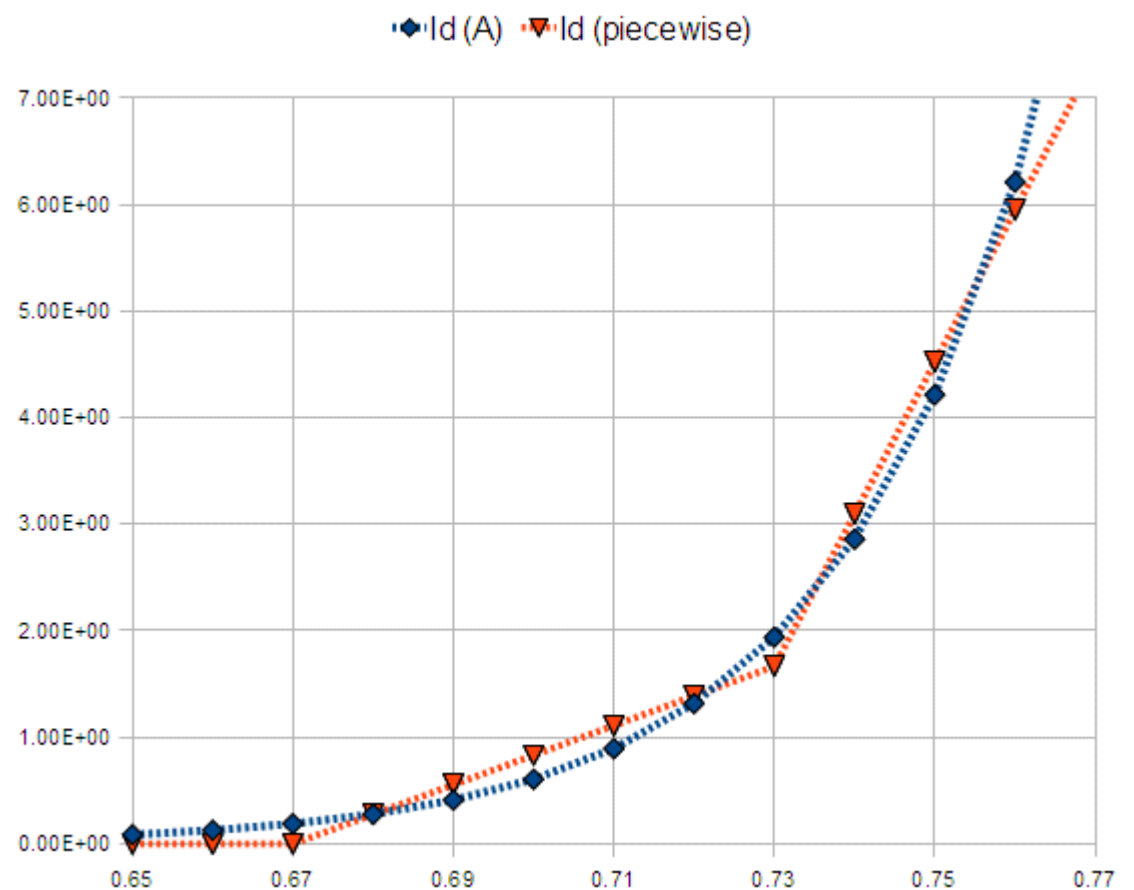


Method of assumed states: 3 possibilities

Diode: Piecewise Linear Approximation

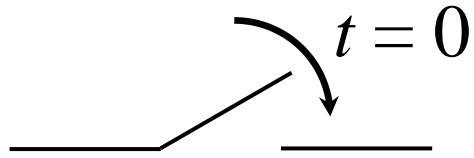


Method of assumed states: 2 possibilities



Method of assumed states: 3 possibilities

Switch vs Unidirectional Device



short circuit $t > 0$

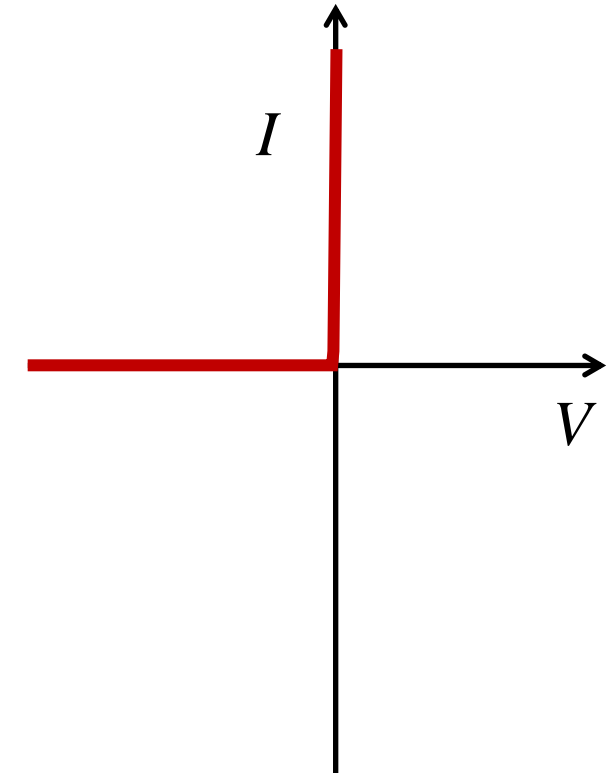
open circuit $t < 0$

Switch: Time-Dependent

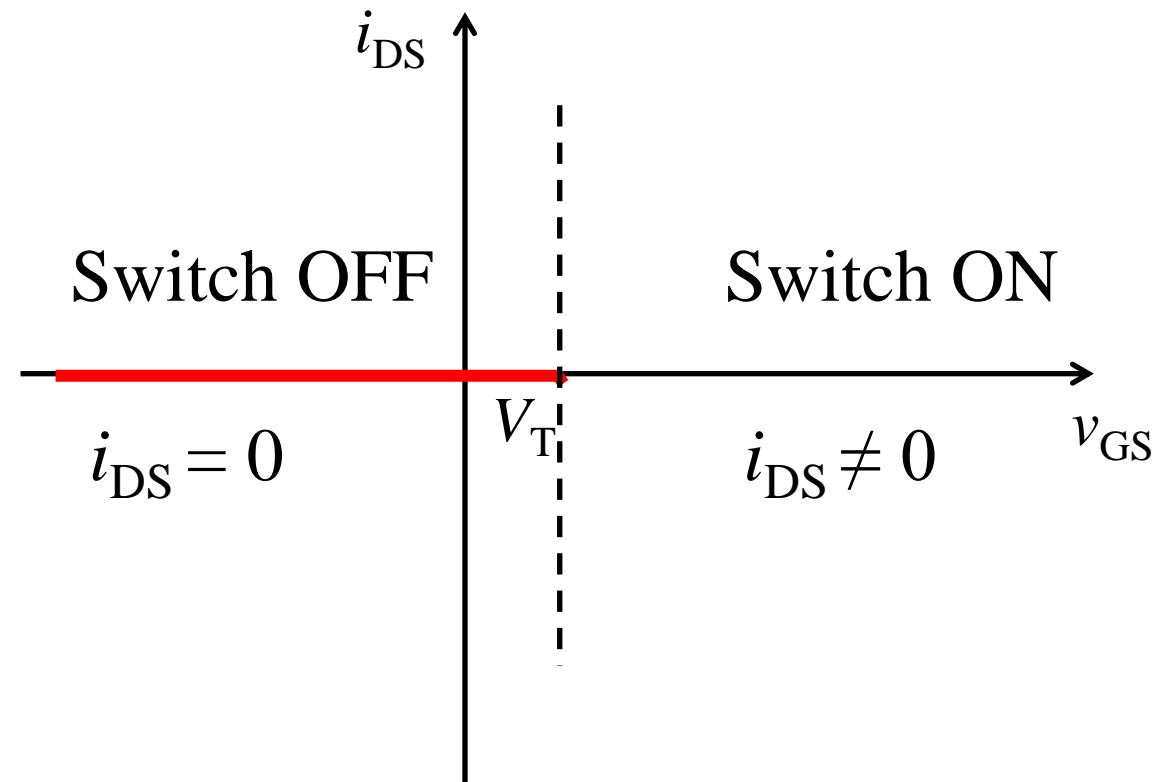
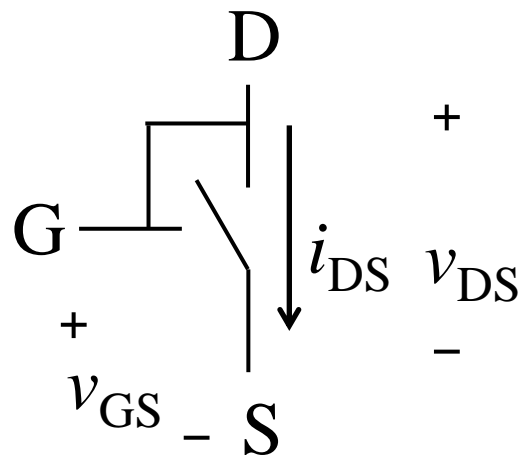
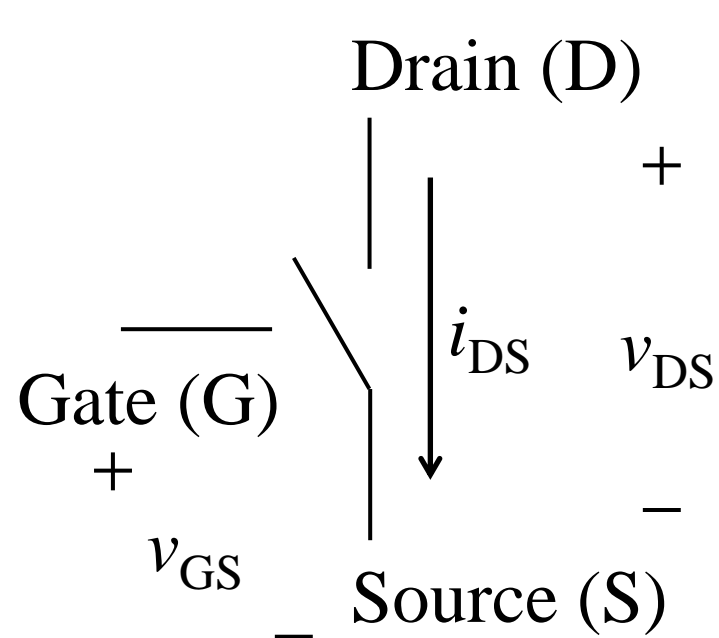
short circuit $V > 0$

open circuit $V < 0$

Diode: Voltage-Dependent

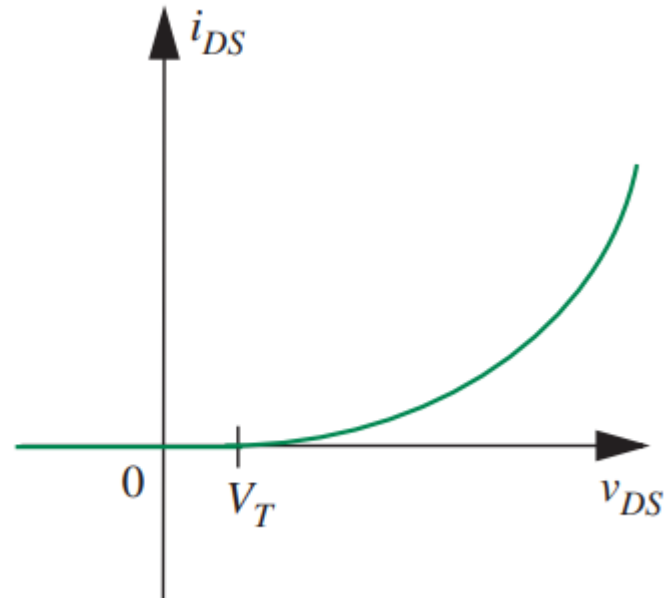
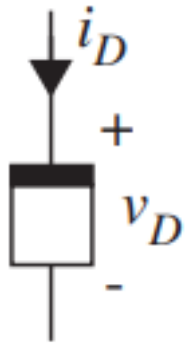


Electrical Switch: Three Terminal Device to Diode



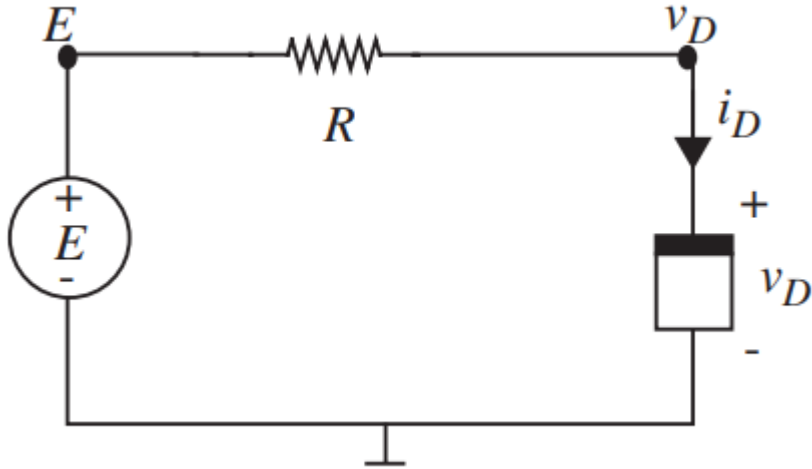
- For $v_{GS} = v_{DS}$, the device is two-terminal and it behaves like an unidirectional device
- Diode-connected transistor (MOSFET)

Unidirectional Device: Square Law



$$i_{DS} = \begin{cases} \frac{K(v_{DS} - V_T)^2}{2} & \text{for } v_{DS} \geq V_T \\ 0 & \text{for } v_{DS} < V_T \end{cases}$$

Square Law Device: Analytical Solution



$$i_D = \begin{cases} Kv_D^2 & \text{for } v_D > 0 \\ 0 & \text{for } v_D \leq 0. \end{cases} \quad V_T = 0$$

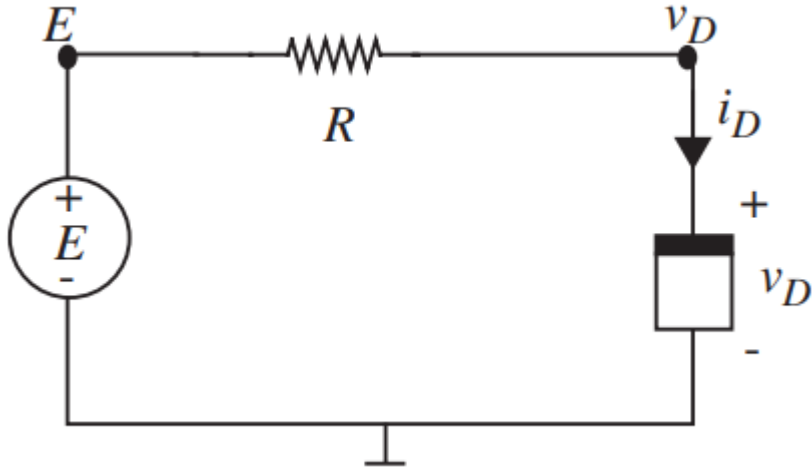
$$\frac{v_D - E}{R} + i_D = 0 \quad i_D = Kv_D^2.$$

$$\frac{v_D - E}{R} + Kv_D^2 = 0.$$

$$RKv_D^2 + v_D - E = 0.$$

$$v_D = \frac{-1 + \sqrt{1 + 4RKE}}{2RK} \quad i_D = K \left[\frac{-1 + \sqrt{1 + 4RKE}}{2RK} \right]^2$$

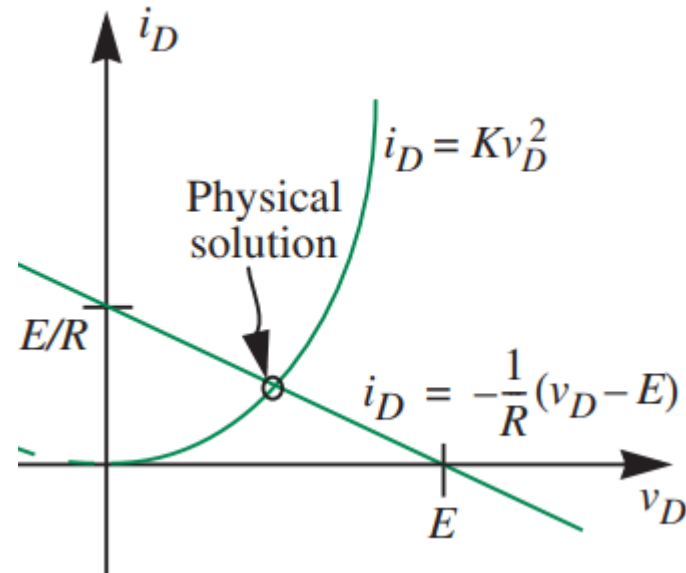
Square Law Device: Graphical Load Line Analysis



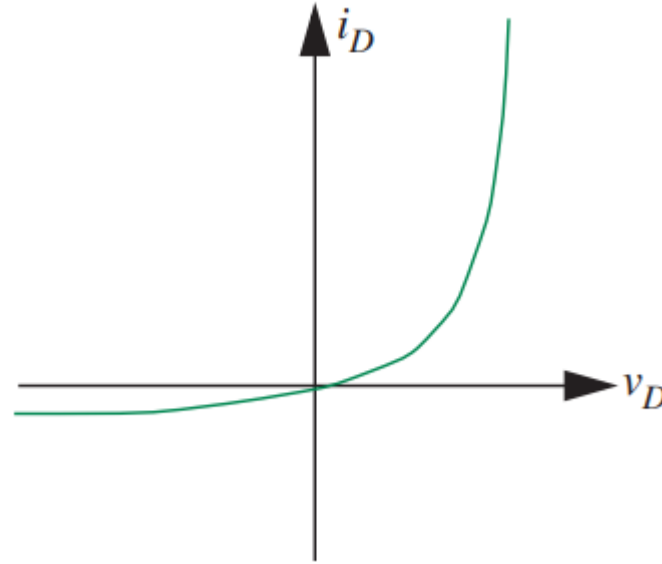
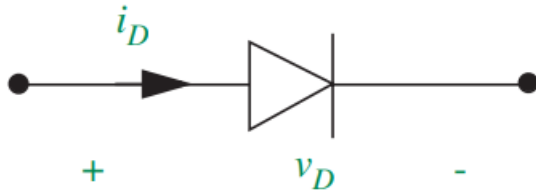
$$i_D = \begin{cases} Kv_D^2 & \text{for } v_D > 0 \\ 0 & \text{for } v_D \leq 0. \end{cases} \quad V_T = 0$$

$$\frac{v_D - E}{R} + i_D = 0 \quad i_D = Kv_D^2.$$

$$i_D = -\frac{v_D - E}{R}$$



Unidirectional Device: Exponential Law



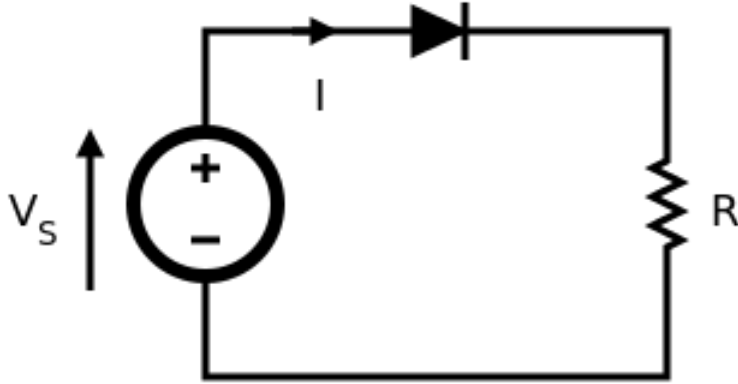
$$i_D = I_S \left(\exp \left(\frac{v_D}{nV_T} \right) - 1 \right), n = 1$$

$$i_D = I_S (e^{v_D/V_{TH}} - 1).$$

$$V_T = V_{TH} = \frac{kT}{q} \approx 26 \text{ mV}$$

at $T = 300\text{K}$

Exponential Law Device: Analytical Solution



$$I = \frac{V_S - V_D}{R} \quad I = I_S \left(\exp \left(\frac{V_D}{nV_T} \right) - 1 \right)$$

$$w = \frac{I_S R}{nV_T} \left(\frac{I}{I_S} + 1 \right) \quad I/I_S = e^{V_D/nV_T} - 1$$

$$we^w = \frac{I_S R}{nV_T} e^{\frac{V_D}{nV_T}} e^{\frac{I_S R}{nV_T} \left(\frac{I}{I_S} + 1 \right)}$$

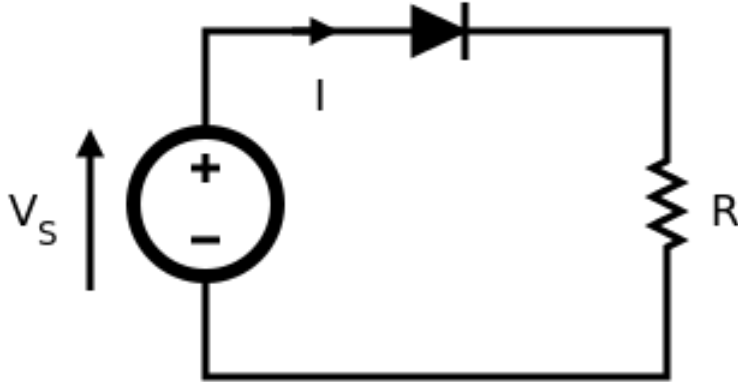
$$we^w = \frac{I_S R}{nV_T} e^{\frac{V_S}{nV_T}} e^{\frac{-IR}{nV_T}} e^{\frac{IR I_S}{nV_T I_S}} e^{\frac{I_S R}{nV_T}}$$

$$we^w = \frac{I_S R}{nV_T} e^{\frac{V_S + I_S R}{nV_T}} = c, \text{ Constant}$$

$$w = W \left(\frac{I_S R}{nV_T} e^{\frac{V_S + I_S R}{nV_T}} \right)$$

$W(c)$ is the Lambert W function
evaluated at the value c

Exponential Law Device: Iterative Solution



$$I = \frac{V_S - V_D}{R}$$

$$I = I_S \left(\exp \left(\frac{V_D}{nV_T} \right) - 1 \right)$$

$$e^{\frac{V_D}{nV_T}} = \frac{I}{I_S} + 1$$

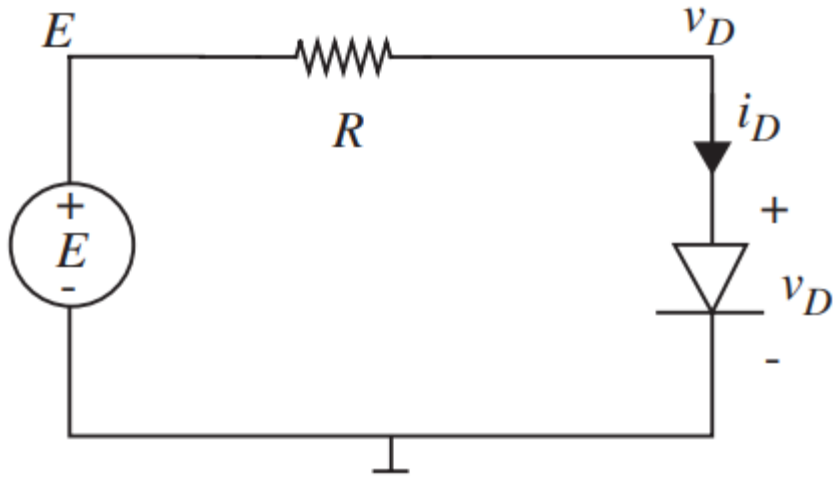
$$\frac{V_D}{nV_T} = \ln \left(\frac{I}{I_S} + 1 \right)$$

$$\frac{V_D}{nV_T} = \ln \left(\frac{V_S - V_D}{RI_S} + 1 \right)$$

$$V_D = nV_T \ln \left(\frac{V_S - V_D}{RI_S} + 1 \right)$$

- Start with an initial guess on the RHS
- Evaluate the LHS to improve upon
- Iterate until desired accuracy is achieved

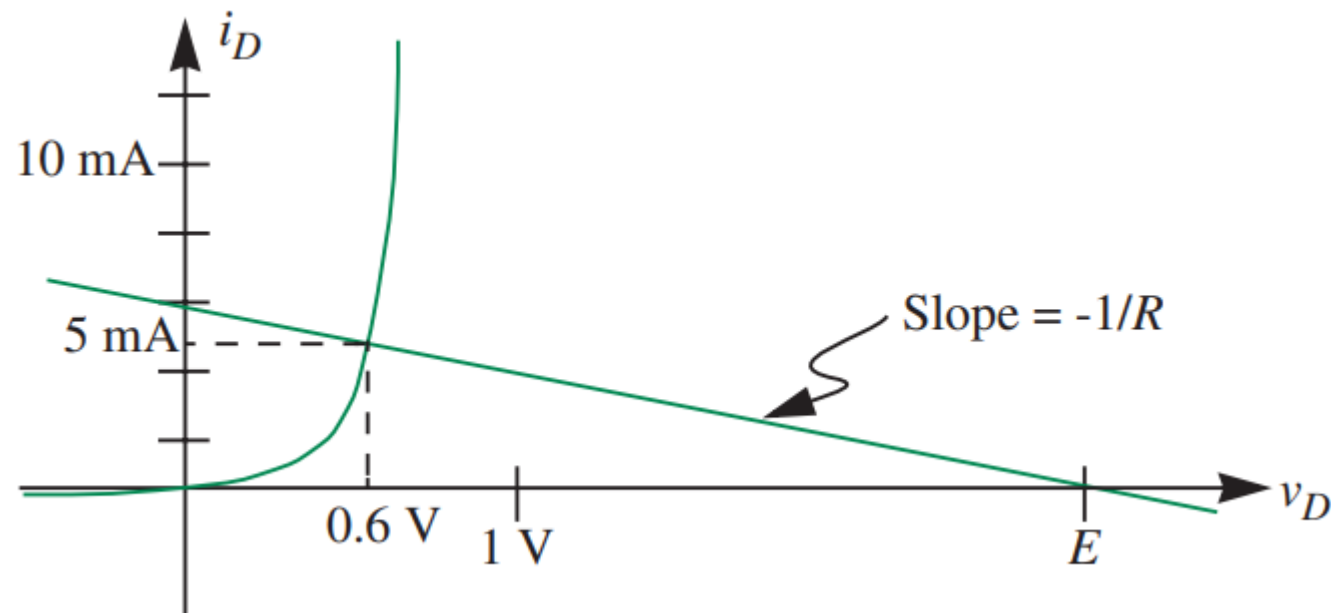
Square Law Device: Graphical Load Line Analysis



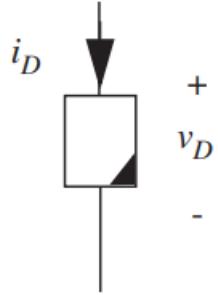
$$\frac{v_D - E}{R} + i_D = 0$$

$$i_D = -\frac{v_D - E}{R}$$

$$i_D = I_S \left(\exp\left(\frac{v_D}{nV_T}\right) - 1 \right)$$

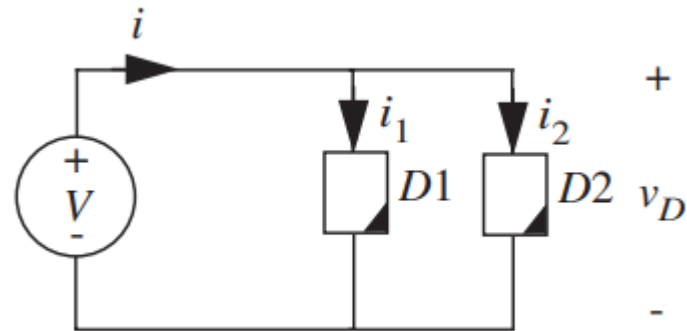


Square Law Device: Parallel Combination



$$i_D = \begin{cases} K v_D^2 & \text{for } v_D > 0 \\ 0 & \text{for } v_D \leq 0. \end{cases}$$

$$V_T = 0$$



$$V = 2 \text{ V}$$

$$K = 0.1 \frac{\text{A}}{\text{V}^2}$$

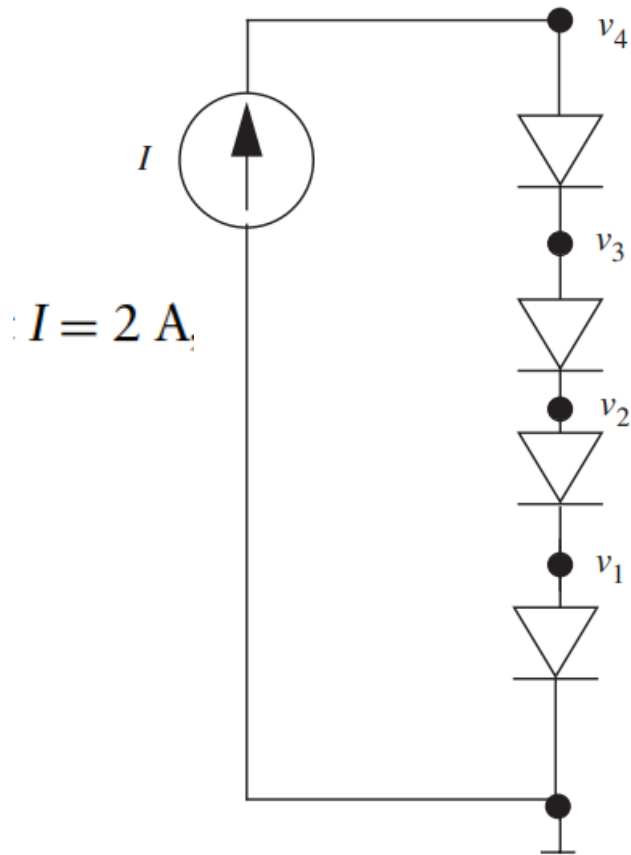
$$v_D = 2 \text{ V}$$

$$i_D = 0.1 v_D^2 = 0.1 \times 2^2 = 0.4 \text{ A}$$

$$i_1 = i_2 = 0.4 \text{ A}$$

$$i = i_1 + i_2 = 0.8 \text{ A}$$

Exponential Law Device: Series Combination



$$i_D = I_s(e^{v_D/V_{TH}} - 1)$$

$$I_s = 10^{-12} \text{ A}, V_{TH} = 0.025 \text{ V}.$$

$$v_1 = 0.025 \ln(10^{12}I + 1) = 0.025 \ln(10^{12} \times 2 + 1) = 0.71 \text{ V}$$

$$v_1 = v_2 - v_1$$

$$v_2 = 2v_1 = 1.42 \text{ V}$$

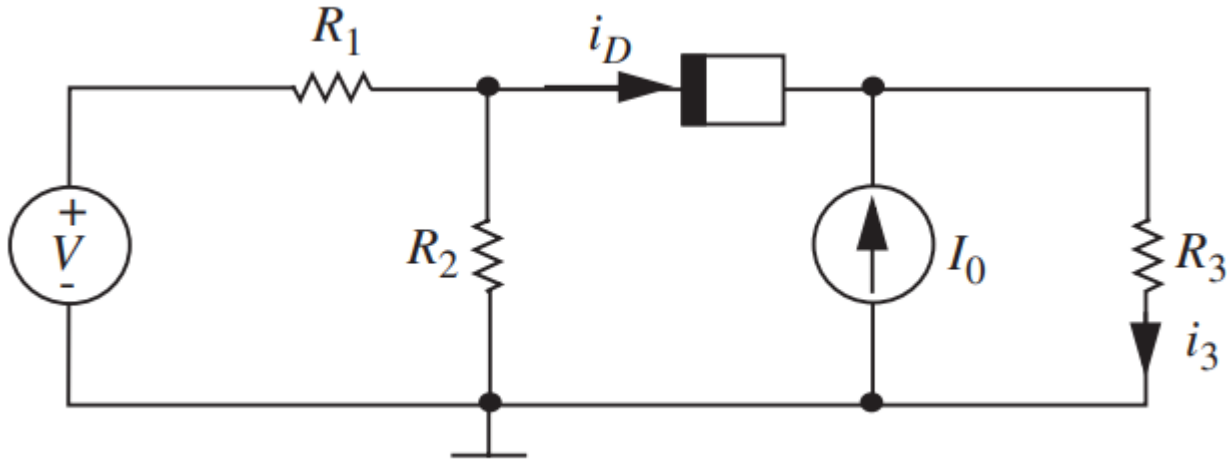
$$v_2 - v_1 = v_3 - v_2$$

$$v_3 = 3v_1 = 2.13 \text{ V}$$

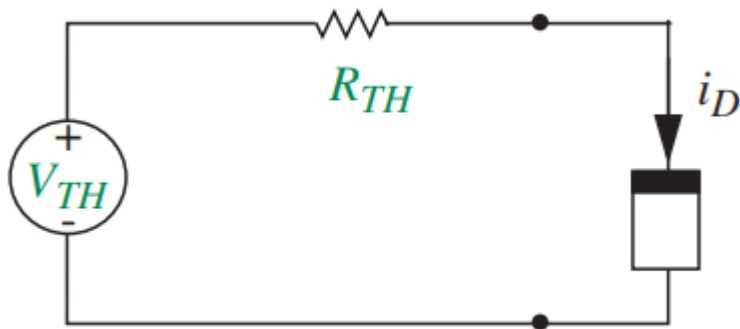
$$v_3 - v_2 = v_4 - v_3$$

$$v_4 = 4v_1 = 2.84 \text{ V}.$$

Square Law Device: Circuit Analysis



$$i_D = \begin{cases} Kv_D^2 & \text{for } v_D > 0 \\ 0 & \text{for } v_D \leq 0. \end{cases}$$

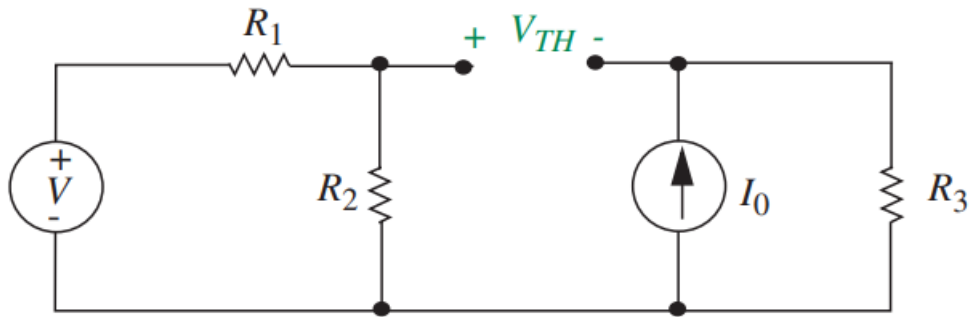
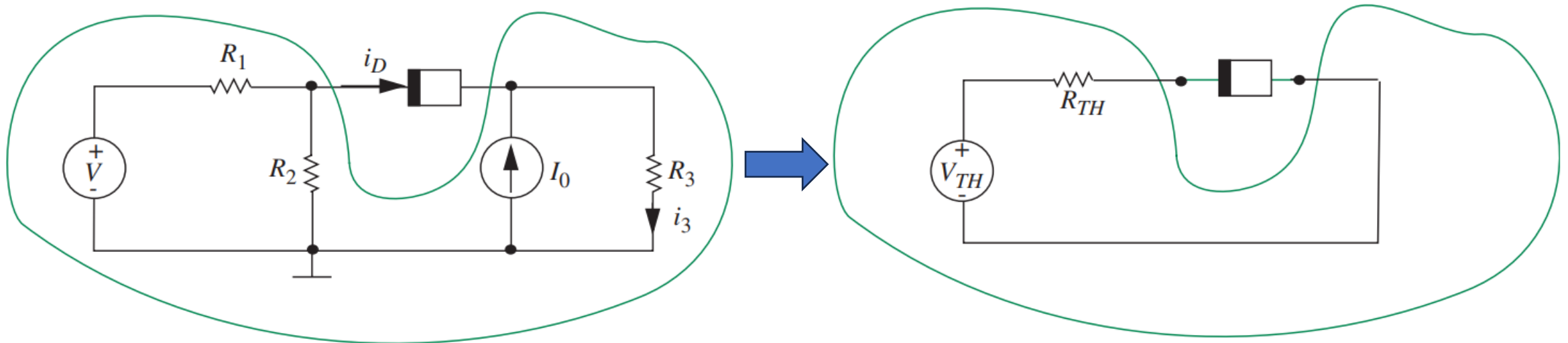


$$v_D = \frac{-1 + \sqrt{1 + 4RKE}}{2RK}$$

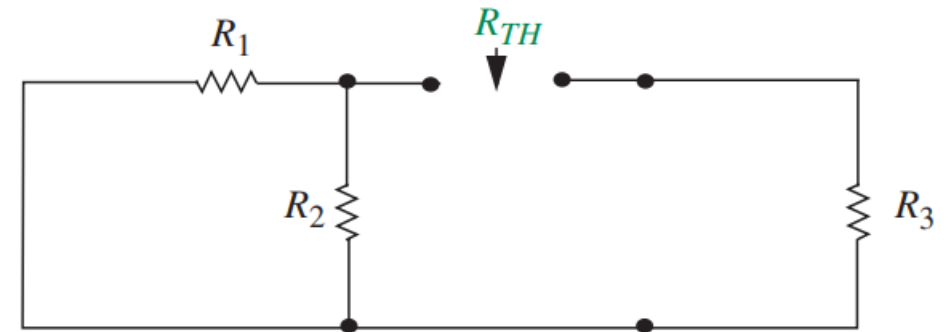
$$E = V_{TH} \quad R = R_{TH}$$

$$i_D = K \left[\frac{-1 + \sqrt{1 + 4RKE}}{2RK} \right]^2$$

Square Law Device: Circuit Analysis

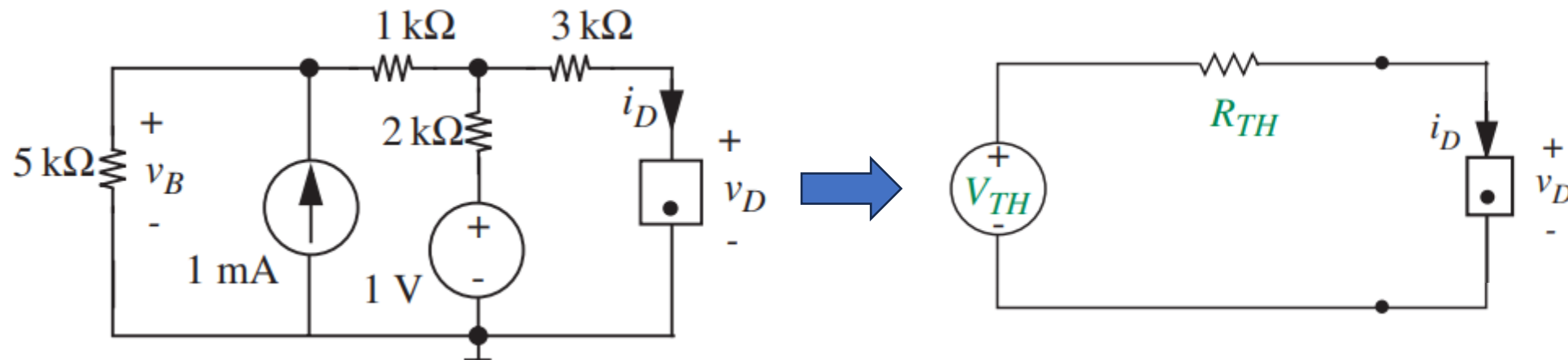
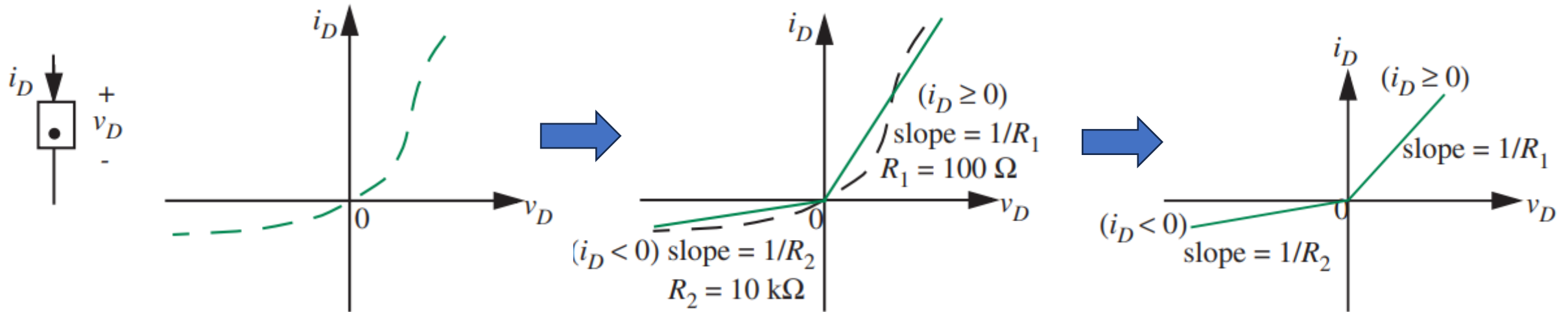


$$V_{TH} = V \frac{R_2}{R_1 + R_2} - I_0 R_3$$



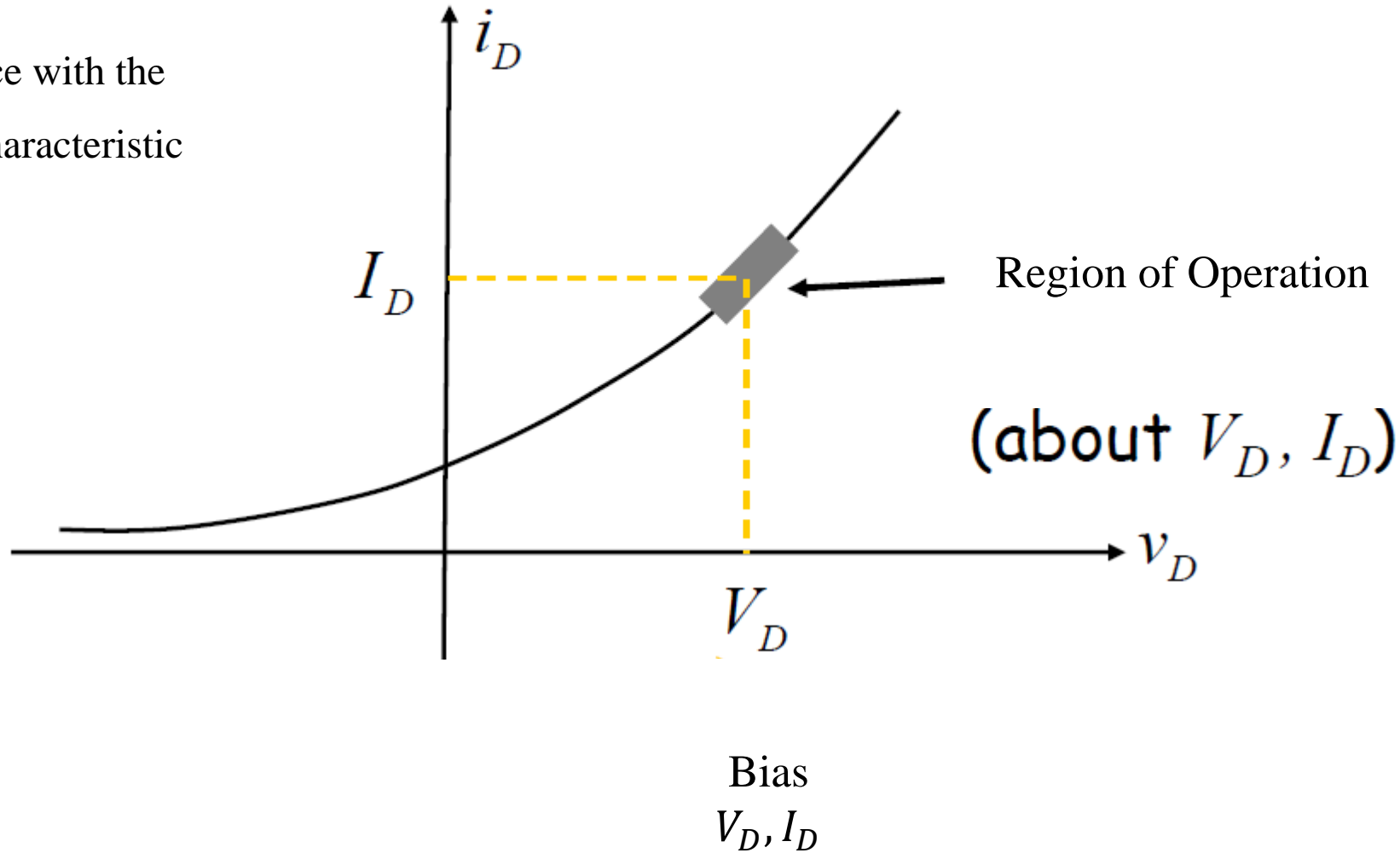
$$R_{TH} = (R_1 || R_2) + R_3$$

Piecewise Linear Approximation: Circuit Analysis

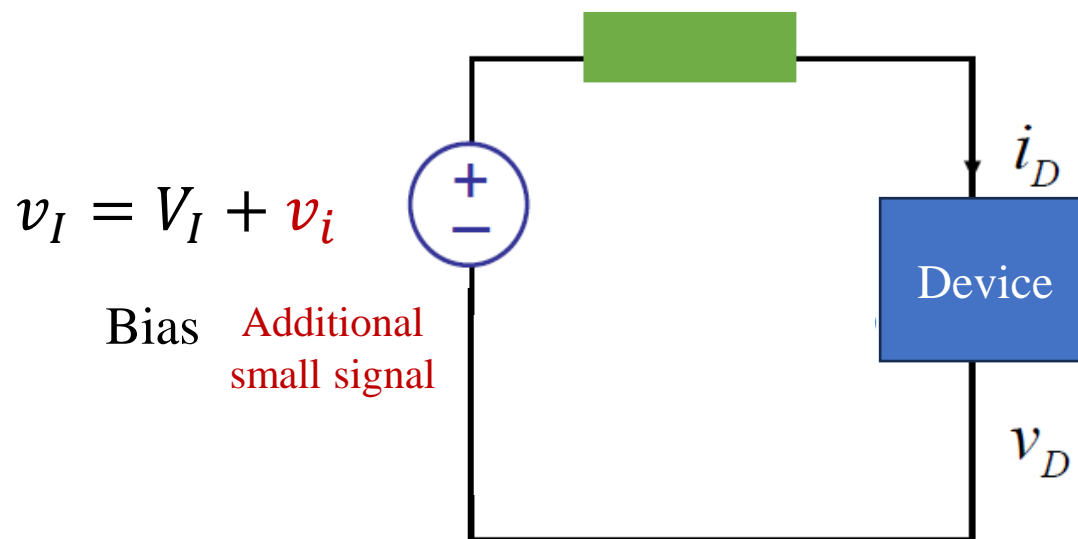
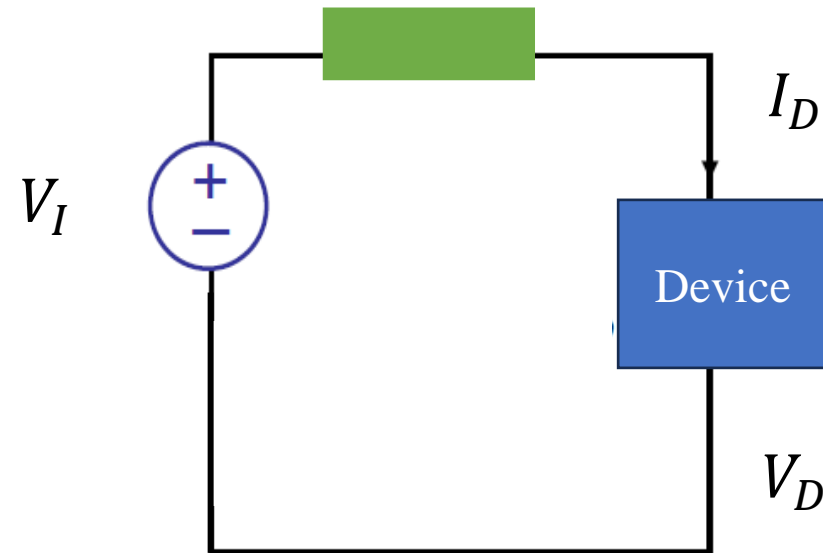
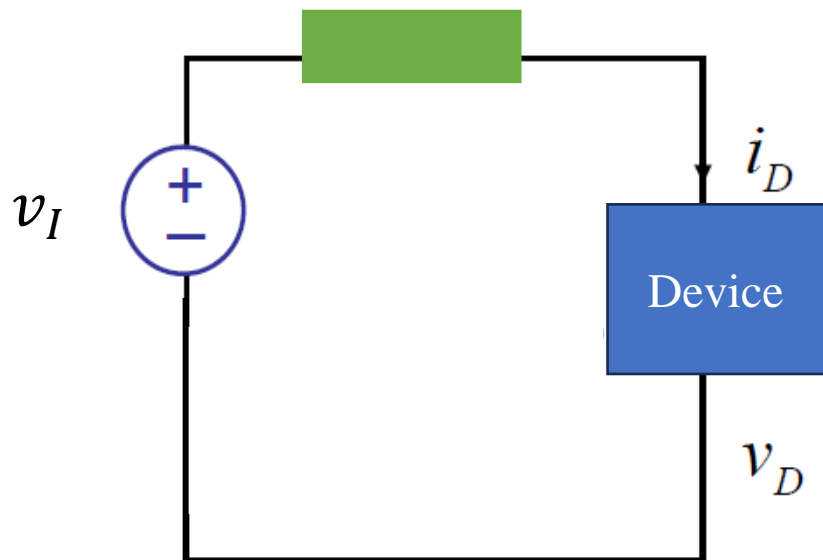


Small Signal Analysis

Consider a device with the following I-V characteristic



Small Signal Analysis



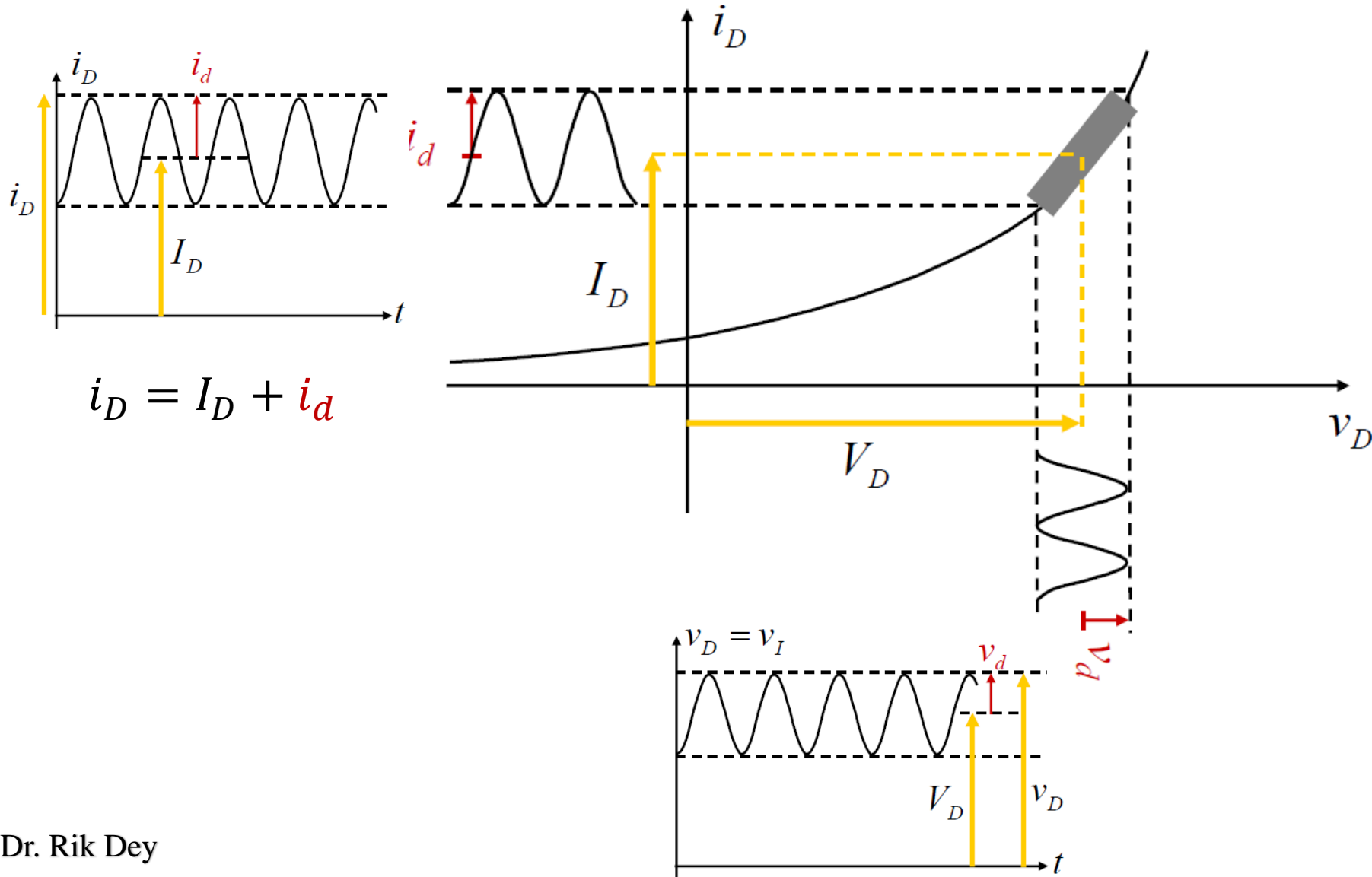
$$i_D = I_D + \textcircled{v_d}$$

Relationship?

$$v_D = V_D + \textcircled{v_d}$$

Superposition is not applicable

Small Signal Analysis Result



Small Signal Analysis Method

- Operate at some bias point V_D, I_D
- Superimpose small signal v_d on top of V_D
- Response i_d to small signal v_d is approximately linear

$$v_D = V_D + v_d$$

signal

Bias

Additional
small signal

$$i_D = I_D + i_d$$

signal

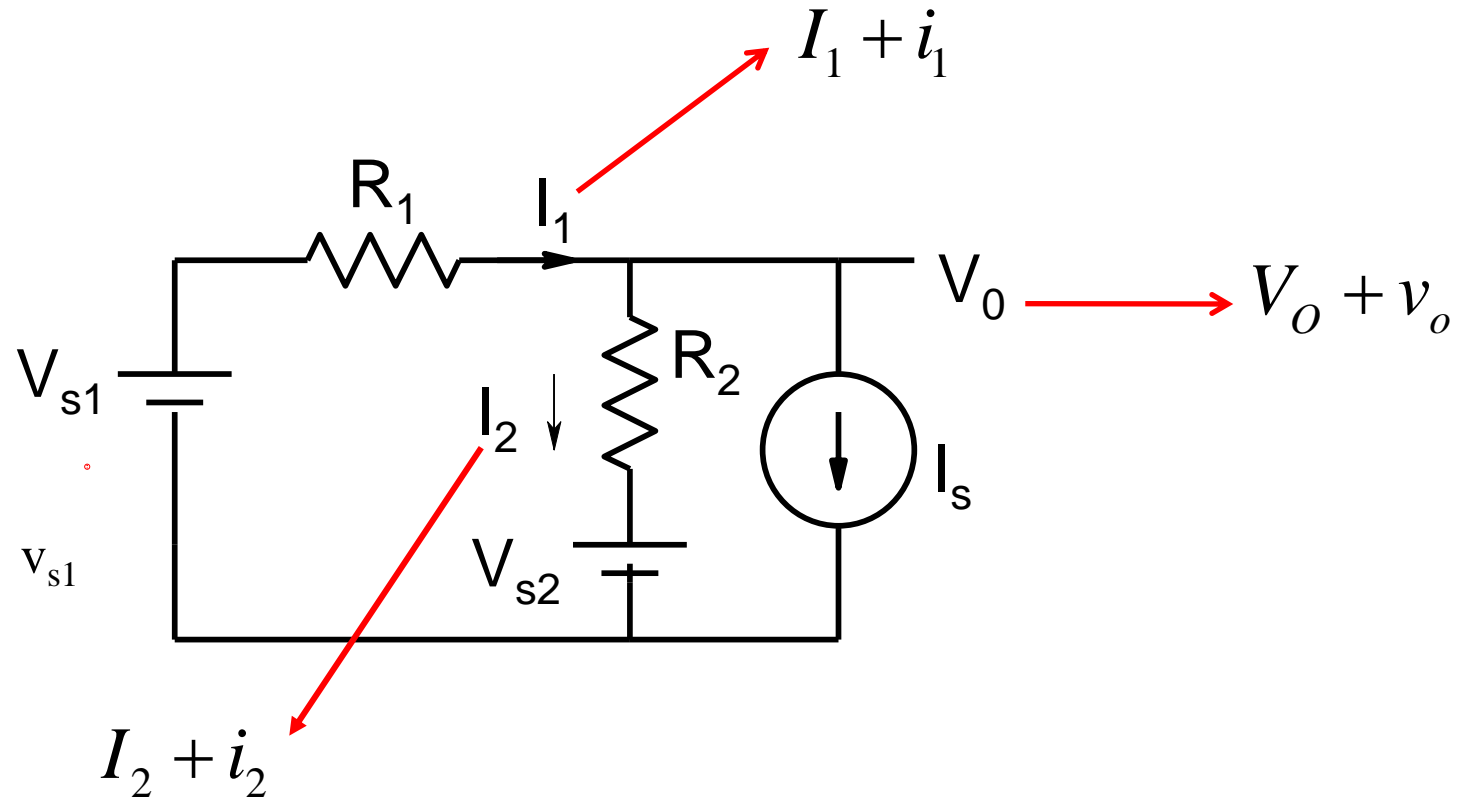
Bias

Additional
small signal

Linear

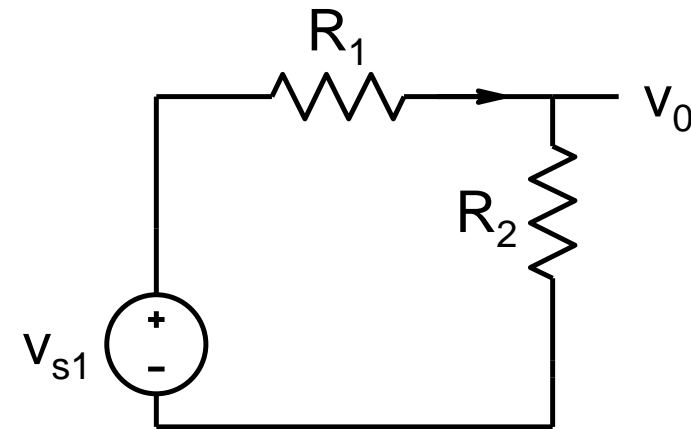
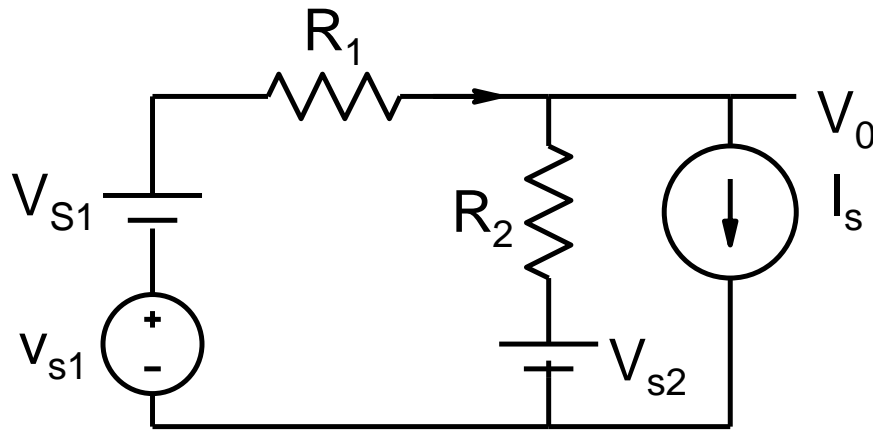
$$i_d = k v_d$$

Incremental Model: General



Incremental Model: General

- Same model for R, C, L
- Voltage source with constant voltage \rightarrow short circuit
- Current source with constant current \rightarrow open circuit



$$v_o = v_{s1} \times \frac{R_2}{R_1 + R_2}$$